

L Number	Hits	Search Text	DB	Time stamp
-	696	(438/400).ccls. and @ad<=20011206	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 11:22
-	6	((438/400).ccls. and @ad<=20011206) and ONO	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 11:26
-	0	@ad<=20011206 and 'ONO structure' with 'buffer layer'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 12:35
-	290	@ad<=20011206 and 'ONO structure'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 12:01
-	160	@ad<=20011206 and 'Oxide' with 'SiON' with 'SiN' with 'SiON' with 'Oxide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 12:31
-	3	@ad<=20011206 and 'ONO structure' and 'buffer layer'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 12:40
-	1	@ad<=20011206 and 'multi dielectric layer' and 'memory'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 12:43
-	26	@ad<=20011206 and 'multi' adj 'dielectric' and 'memory'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 12:47
-	0	@ad<=20011206 and 'O-SiON-N-SiON-O'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 12:49
-	1393	@ad<=20011206 and oxide and SiON and Nitride and SiON and oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 12:55
-	0	@ad<=20011206 and oxide adj SiON adj Nitride adj SiON adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 12:56
-	300	@ad<=20011206 and 'oxide' with 'SiON' with 'nitride' with 'SiON' with 'oxide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 14:31
-	107	(@ad<=20011206 and 'oxide' with 'SiON' with 'nitride' with 'SiON' with 'oxide') and memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 09:13
-	540	@ad<=20011206 and (438/778).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/17 14:32

-	2862	((438/778) or (438/787) or (438/790-791) or (438/794) or (438/400) or (438/769-770) or (438/770) or (438/775)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 08:49
-	2356	((257/324) or (257/314-315) or (257/406) or (257/410)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 08:41
-	7	((438/778) or (438/787) or (438/790-791) or (438/794) or (438/400) or (438/769-770) or (438/770) or (438/775)).CCLS.) and @ad<=20011206 and 'silane' with 'nitrogen oxide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 08:59
-	6328	((438/778) or (438/787) or (438/790-791) or (438/794) or (438/400) or (438/769-770) or (438/770) or (438/775)).CCLS.) and @ad<=20011206 and 'SiON' or 'silicon oxynitride'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 09:03
-	0	((438/778) or (438/787) or (438/790-791) or (438/794) or (438/400) or (438/769-770) or (438/770) or (438/775)).CCLS.) and @ad<=20011206 and SiH4 with N2O with NH3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 09:04
-	8	((438/778) or (438/787) or (438/790-791) or (438/794) or (438/400) or (438/769-770) or (438/770) or (438/775)).CCLS.) and @ad<=20011206 and 'SiON' with 'deposition'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 09:09
-	448	((438/778) or (438/787) or (438/790-791) or (438/794) or (438/400) or (438/769-770) or (438/770) or (438/775)).CCLS.) and @ad<=20011206 and 'ammonia'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 09:11
-	190	((438/778) or (438/787) or (438/790-791) or (438/794) or (438/400) or (438/769-770) or (438/770) or (438/775)).CCLS.) and @ad<=20011206 and 'ammonia' and 'silane'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 09:11
-	194	@ad<=20011206 and 'ammonia' and 'silane' and 'nitrogen oxide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 09:16
-	359	@ad<=20011206 and 'oxide' with 'SiON' with 'nitride' with 'SiON' with 'oxide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 09:13
-	27	@ad<=20011206 and 'ammonia' same 'silane' same 'nitrogen oxide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/28 09:19